

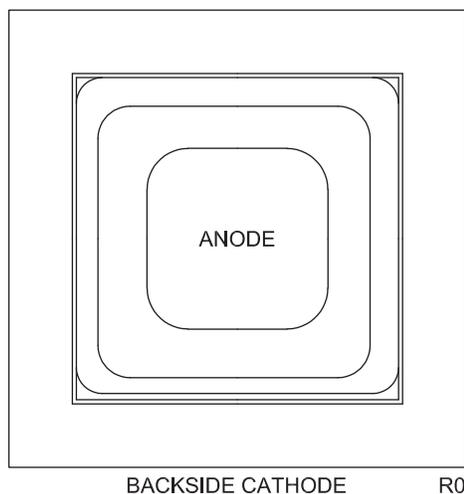
**PROCESS CPZ34R**  
**Transient Voltage Suppressor**  
6.2 Volt TVS Chip



**PROCESS DETAILS**

Die Size	6.7 x 6.7 MILS
Die Thickness	3.54 MILS
Anode Bonding Pad Area	4.5 x 4.5 MILS
Top Side Metalization	Al - 30,000Å
Back Side Metalization	Au.As - 12,000Å

**GEOMETRY**



**GROSS DIE PER 5 INCH WAFER**

374,272

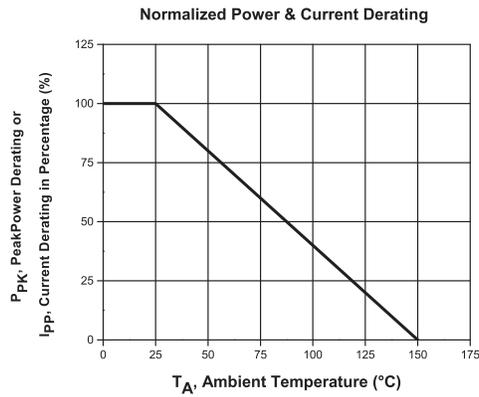
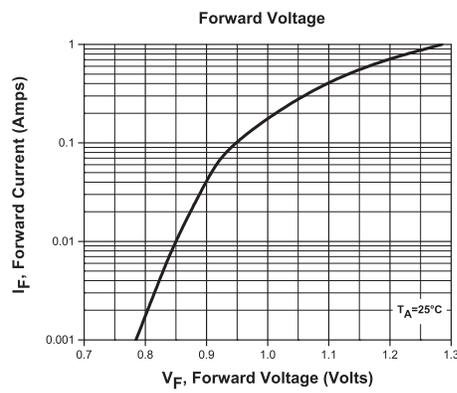
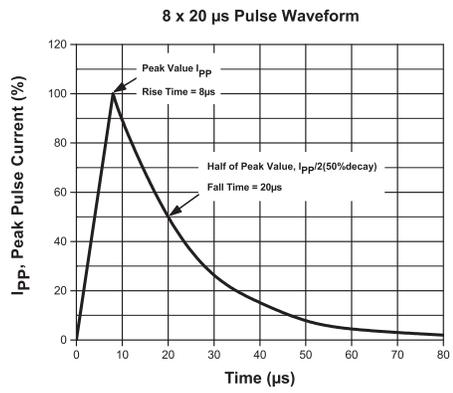
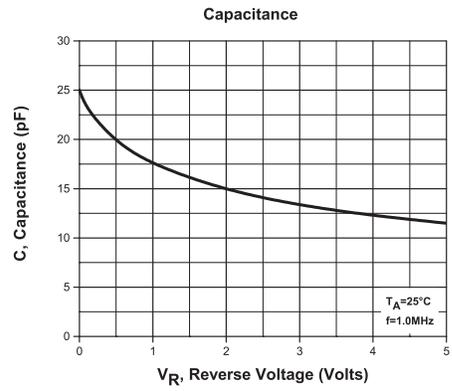
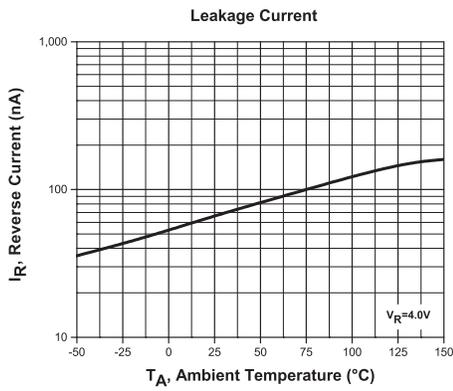
**PRINCIPAL DEVICE TYPE**

CTLTVS6V2

R0 (17-January 2013)

# PROCESS CPZ34R

## Typical Electrical Characteristics



R0 (17-January 2013)